OMRON

MOS FET Relays

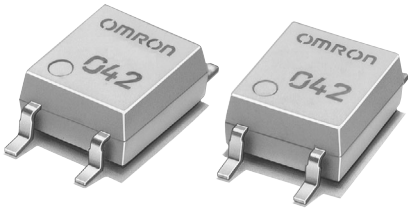
G3VM-81GR1

New MOS FET Relays Designed for Switching Minute Signals and Analog Signals.

- New models for 80-V loads.
- Low C × R of 32.5 pF•Ω.
- Dielectric strength of 1,500 Vrms between I/O.

RoHS compliant

⚠ Refer to *"Common Precautions"*.



Note: The actual product is marked differently from the image shown here.

■ Application Examples

- Broadband systems
- Data loggers
- Measurement devices
- Amusement machines

■ List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Minimum packaging unit	
				Number per stick	Number per tape
SPST-NO	Surface-mounting terminals	80 VAC	G3VM-81GR1	100	---
			G3VM-81GR1 (TR)	---	2,500

■ Dimensions

Note: All units are in millimeters unless otherwise indicated.

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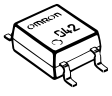

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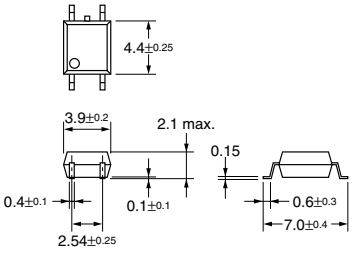
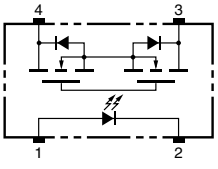


Weight: 0.1 g

■ Terminal Arrangement/Internal Connections (Top View)

G3VM-81GR1



■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

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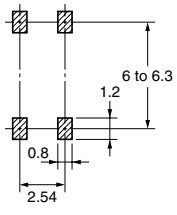


■ Absolute Maximum Ratings (Ta = 25°C)

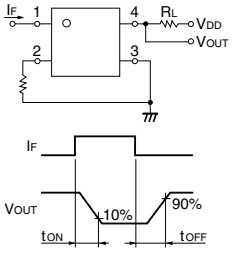
Item		Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current	I_F	50	mA	
	Repetitive peak LED forward current	I_{FP}	1	A	
	LED forward current reduction rate	ΔI_F/°C	–0.5	mA/°C	Ta ≥ 25°C
	LED reverse voltage	V_R	5	V	
	Connection temperature	T_j	125	°C	
Output	Output dielectric strength	V_{OFF}	80	V	
	Continuous load current	I_O	200	mA	
	ON current reduction rate	ΔI_O/°C	–2.0	mA/°C	Ta ≥ 25°C
	Connection temperature	T_j	125	°C	
Dielectric strength between input and output (See note 1.)		V_{I-O}	1,500	Vrms	AC for 1 min
Ambient operating temperature		T_a	–20 to +85	°C	With no icing or condensation
Storage temperature		T_{stg}	–40 to +125	°C	With no icing or condensation
Soldering temperature		---	260	°C	10 s

Note: **1.** The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

■ Electrical Characteristics (Ta = 25°C)

Item		Symbol	Minimum	Typical	Maximum	Unit	Measurement conditions
Input	LED forward voltage	V_F	1.0	1.15	1.3	V	I_F = 10 mA
	Reverse current	I_R	---	---	10	μA	V_R = 5 V
	Capacity between terminals	C_T	---	15	---	pF	V = 0, f = 1 MHz
	Trigger LED forward current	I_{FT}	---	---	3	mA	I_O = 200 mA
Output	Maximum resistance with output ON	R_{ON}	---	5	8	Ω	I_F = 5 mA, I_O = 200 mA
	Current leakage when the relay is open	I_{LEAK}	---	---	1	nA	V_{OFF} = 80 V, Ta = 50°C
	Capacity between terminals	C_{OFF}	---	6.5	11	pF	V = 0, f = 100 MHz, t < 10 s
Capacity between I/O terminals		C_{I-O}	---	0.7	---	pF	f = 1 MHz, Vs = 0 V
Insulation resistance between I/O terminals		R_{I-O}	1,000	---	---	MΩ	V_{I-O} = 500 VDC, RoH ≤ 60%
Turn-ON time		tON	---	0.13	0.5	ms	I_F = 5 mA, R_L = 200 Ω, V_{DD} = 10 V (See note 2.)
Turn-OFF time		tOFF	---	0.17	0.5	ms	

Note: **2.** Turn-ON and Turn-OFF Times



■ Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V_{DD}	---	---	64	V
Operating LED forward current	I_F	5	---	30	mA
Continuous load current	I_O	---	---	200	mA
Operating temperature	T_a	25	---	60	°C

■ Engineering Data

Load Current vs. Ambient Temperature

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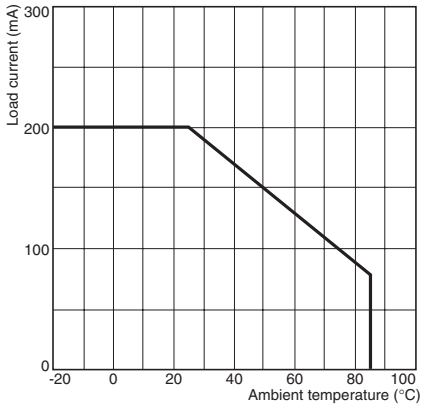

■ Safety Precautions

Refer to *"Common Precautions"* for all G3VM models.